

# 350kHz, 16V Rail-to-Rail Input/Output Micro Power Operational Amplifiers

#### **Features**

■ Low Quiescent Current: 25µA at 12V supply 15µA at 5V supply

■ Gain Bandwidth Product: 350kHz

■ Operates on 2.7V ~ 16V Supplies

■ Slew Rate: 0.2V/µs

■ Rail-to-Rail Input and Output (RRIO)

Unity Gain Stable

No Phase Reversal

■ Extended Temperature Ranges
From -40°C to +125°C

Small Packaging
 COS2251 available in SOT23-5/SOP-8
 COS2252 available in SOP-8/MSOP-8
 COS2254 available in SOP14/TSSOP14

## **Applications**

- White Goods
- Portable Equipment
- Sensor Conditioning
- Analog Active Filters
- Configuration control and Print Support
- Battery Powered Systems
- Transducer Interfaces

## **General Description**

The COS2251 (single), COS2252 (dual) and COS2254 (quad) are micro power, rail-to-rail input and output amplifiers operated on 3V to 16V supplies. Despite their low quiescent current, the COS225x family provides excellent overall performance and versatility. They have both rail-to-rail input and output range. The output voltage swing extends to within 30mV of each rail, providing the maximum output dynamic range with excellent overdrive recovery.

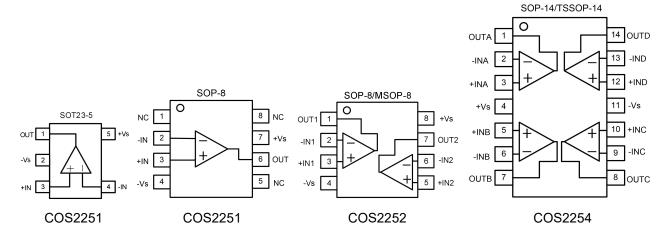
COS2251/2/4 family is unity gain stable and has a gain bandwidth product of 350kHz (typical). They provide high CMRR and PSRR performance and can operate from a single supply voltage as high as 16V. These features make the COS2251/2/4 family well suited for single-supply, battery-powered applications. They can be used as plus-in replacements for many commercially available op-amps to reduce power and improve input/output range and performance.

Rev1.2
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# 1. Pin Configuration and Functions



## **Pin Functions**

Name	Description	Note
+Vs	Positive power supply	A bypass capacitor of 0.1µF as close to the part as possible should be placed between power supply pins or between supply pins and ground.
-Vs	Negative power supply or ground	If it is not connected to ground, bypass it with a capacitor of 0.1µF as close to the part as possible.
-IN	Negative input	Inverting input of the amplifier. Voltage range of this pin can go from -Vs -0.3V to +Vs + 0.3V.
+IN	Positive input	Non-inverting input of the amplifier. This pin has the same voltage range as –IN.
OUT	Output	The output voltage range extends to within millivolts of each supply rail.
NC	No connection	

# 2. Package and Ordering Information

Model	Channel	Order Number	Package	Package Option	Marking Information
COS2251	1	COS2251TR	SOT23-5	Tape and Reel, 3000	C2251
0082251	COS2251SR	SOP-8	Tape and Reel, 4000	COS2251	
CO22252	0000050	COS2252SR	SOP-8	Tape and Reel, 4000	COS2252SR
COS2252 2		COS2252MR	MSOP-8	Tape and Reel, 4000	COS2252MR
COS2254 4		COS2254SR	SOP-14	Tape and Reel, 3000	COS2254SR
		COS2254TR	TSSOP-14	Tape and Reel, 3000	COS2254TR



## 3. Product Specification

## 3.1 Absolute Maximum Ratings (1)

Parameter	Rating	Units
Power Supply: +Vs to -Vs	16	V
Input Voltage	-Vs -0.5V to +Vs + 0.5V	V
Input Current (2)	10	mA
Storage Temperature Range	-65 to 150	°C
Junction Temperature	150	°C
Operating Temperature Range	-40 to 125	°C
ESD Susceptibility, HBM	2000	V

<sup>(1)</sup> Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

#### 3.2 Thermal Data

Parameter	Rating	Unit
Package Thermal Resistance, R <sub>θJA</sub> (Juntion-to-ambient)	190 (SOT23-5) 206 (MSOP8) 155 (SOP8) 105 (TSSOP14) 82 (SOP14)	°C/W

## 3.3 Recommended Operating Conditions

Parameter	Rating	Unit
DC Supply Voltage	3 ~ 12	V
Input common-mode voltage range	-Vs ~ +Vs	V
Operating ambient temperature	-40 to +85	°C

<sup>(2)</sup> Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current-limited to 10mA or less.



## 3.4 Electrical Characteristics

(+Vs=+12V, -Vs=0, VcM=Vs/2, TA=+25°C, RL=10k $\Omega$  to Vs/2, unless otherwise noted)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input Characteristics	1			1		
Input Offset Voltage	Vos			±0.6	±5	mV
Input Offset Voltage Drift	ΔV <sub>OS</sub> /ΔΤ	-40 to 125°C		±1.0		μV/°C
Input Bias Current	IB			±1		pA
Input Offset Current	los			±1		pA
Common-Mode Voltage Range	V <sub>СМ</sub>		-0.1		12.1	V
Common-Mode Rejection Ratio	CMRR	V <sub>CM</sub> =0.1V to 15.9V		125		dB
Open-Loop Voltage Gain	AOL	V <sub>0</sub> =0.2V to 15.8V		120		dB
Output Characteristics						
		R <sub>L</sub> =1MΩ		3		mV
Output Voltage Swing from Rail		R <sub>L</sub> =100kΩ		30		mV
		R <sub>L</sub> =10kΩ		300		mV
Short-Circuit Current	I <sub>SR</sub>			±50		mA
Power Supply	1					
Operating Voltage Range			3		16	V
Power Supply Rejection Ratio	PSRR	V <sub>S</sub> = 3.5V to 16V	80	100		dB
		V <sub>S</sub> =12V		25		μA
Quiescent Current / Amplifier	IQ	V <sub>S</sub> =5V		15		μA
		V <sub>S</sub> =2.7V		10		μA
Dynamic Performance						
Gain Bandwidth Product	GBWP	G=+1		350		kHz
Slew Rate	SR	G = +1 , 2V Output Step		0.2		V/µs
Noise Performance				•	1	
Voltage Noise Density	e <sub>n</sub>	f=1kHz		72		nV/ √ Hz



## 4.0 Application Notes

#### **Driving Capacitive Loads**

Driving large capacitive loads can cause stability problems for voltage feedback op amps. As the load capacitance increases, the feedback loop's phase margin decreases, and the closed loop bandwidth is reduced. This produces gain peaking in the frequency response, with overshoot and ringing in the step response. A unity gain buffer (G = +1) is the most sensitive to capacitive loads, but all gains show the same general behavior.

When driving large capacitive loads with these op amps (e.g., > 100 pF when G = +1), a small series resistor at the output (R<sub>ISO</sub> in Figure 1) improves the feedback loop's phase margin (stability) by making the output load resistive at higher frequencies. It does not, however, improve the bandwidth.

To select  $R_{ISO}$ , check the frequency response peaking (or step response overshoot) on the bench. If the response is reasonable, you do not need  $R_{ISO}$ . Otherwise, start  $R_{ISO}$  at 1 k $\Omega$  and modify its value until the response is reasonable.

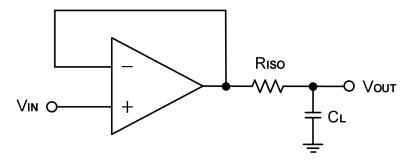


Figure 1. Indirectly Driving Heavy Capacitive Load

An improvement circuit is shown in Figure 2. It provides DC accuracy as well as AC stability.  $R_F$  provides the DC accuracy by connecting the inverting signal with the output,  $C_F$  and  $R_{ISO}$  serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving phase margin in the overall feedback loop.

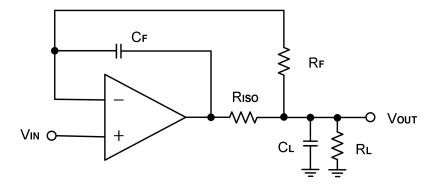


Figure 2. Indirectly Driving Heavy Capacitive Load with DC Accuracy



For noninverting configuration, there are two others ways to increase the phase margin: (a) by increasing the amplifier's gain or (b) by placing a capacitor in parallel with the feedback resistor to counteract the parasitic capacitance associated with inverting node, as shown in Figure 3.

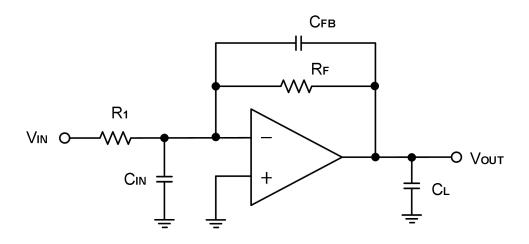


Figure 3. Adding a Feedback Capacitor in the Noninverting Configuration

#### **Power-Supply Bypassing and Layout**

The COS2251/2/4 operates from a single +2.7V to +16V supply or dual  $\pm 1.35V$  to  $\pm 8V$  supplies. For single-supply operation, bypass the power supply +Vs with a  $0.1\mu F$  ceramic capacitor which should be placed close to the +Vs pin. For dual-supply operation, both the +Vs and the -Vs supplies should be bypassed to ground with separate  $0.1\mu F$  ceramic capacitors.  $2.2\mu F$  tantalum capacitor can be added for better performance.

The length of the current path is directly proportional to the magnitude of parasitic inductances and thus the high frequency impedance of the path. High speed currents in an inductive ground return create an unwanted voltage noise. Broad ground plane areas will reduce the parasitic inductance. Thus a ground plane layer is important for high speed circuit design.

#### **Typical Application Circuits**

#### **Differential Amplifier**

The circuit shown in Figure 4 performs the differential function. If the resistors ratios are equal  $(R_4 / R_3 = R_2 / R_1)$ , then  $V_{OUT} = (V_{IP} - V_{IN}) \times R_2 / R_1 + V_{REF}$ .



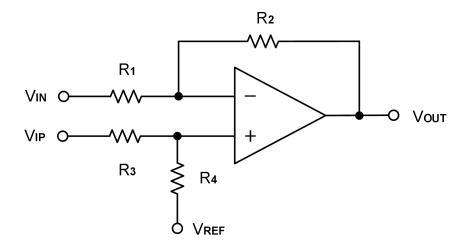


Figure 4. Differential Amplifier

#### **Low Pass Active Filter**

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to establish this limited bandwidth is to place an RC filter at the noninverting terminal of the amplifier. If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task, as Figure 5. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to follow this guideline can result in reduction of phase margin. The large values of feedback resistors can couple with parasitic capacitance and cause undesired effects such as ringing or oscillation in high-speed amplifiers. Keep resistors value as low as possible and consistent with output loading consideration.

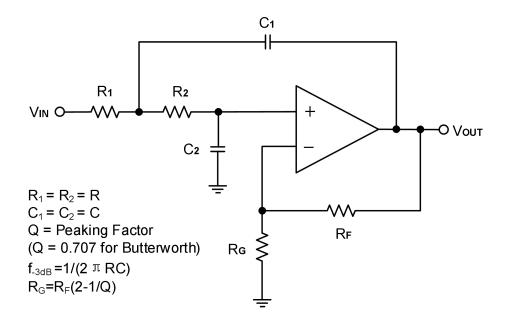
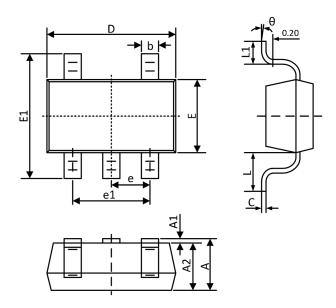


Figure 5. Two-Pole Low-Pass Sallen-Key Active Filter



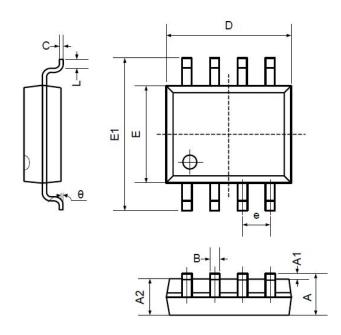
# 5. Package Information

## **5.1 SOT23-5 (Package Outline Dimensions)**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.400	0.012	0.016
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.95	ОТҮР	0.03	7TYP
e1	1.800	2.000	0.071	0.079
L	0.700REF		0.02	8REF
L1	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

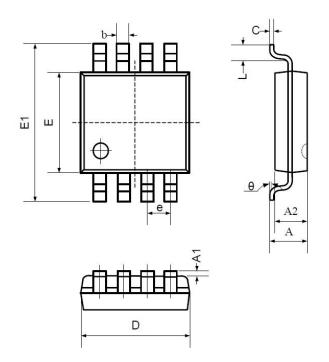
## 5.2 SOP8 (Package Outline Dimensions)



Symbol		nsions meters	Dimensions In Inches	
	Min	Max	Min	Max
Α	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
В	0.330	0.510	0.013	0.020
С	0.190	0.250	0.007	0.010
D	4.780	5.000	0.188	0.197
E	3.800	4.000	0.150	0.157
E1	5.800	6.300	0.228	0.248
е	1.270	TYP	0.050	TYP
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

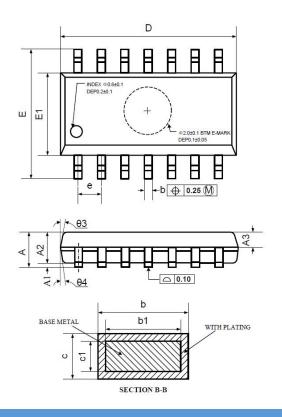


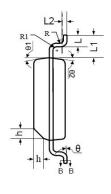
## **5.3 MSOP8 (Package Outline Dimensions)**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
Α	0.800	1.200	0.031	0.047
A1	0.000	0.200	0.000	0.008
A2	0.760	0.970	0.030	0.038
b	0.30	TYP	0.012 TYP	
С	0.15	TYP	0.006 TYP	
D	2.900	3.100	0.114	0.122
е	0.65	TYP	0.026	TYP
E	2.900	3.100	0.114	0.122
E1	4.700	5.100	0.185	0.201
L	0.410	0.650	0.016	0.026
θ	0°	6°	0°	6°

## 5.4 SOP14 (Package Outline Dimensions)

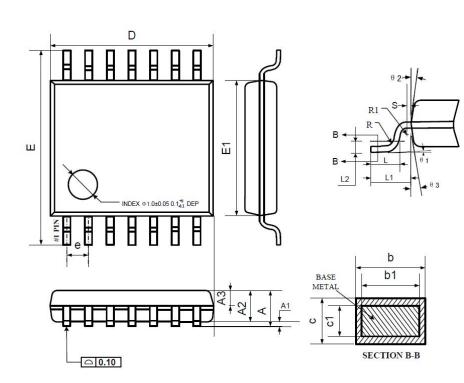




Symbol	Dimensions In Millimeters			
	MIN	NOM	MAX	
Α	1.35	1.60	1.75	
A1	0.10	0.15	0.25	
A2	1.25	1.45	1.65	
A3	0.55	0.65	0.75	
b	0.36		0.49	
b1	0.35	0.40	0.45	
С	0.16		0.25	
c1	0.15	0.20	0.25	
D	8.53	8.63	8.73	
E	5.80	6.00	6.20	
E1	3.80	3.90	4.00	
е		1.27 BS0	3	
L	0.45	0.60	0.80	
L1		1.04 REI		
L2		0.25 BS0		
R	0.07			
R1	0.07			
h	0.30	0.40	0.50	
θ	0°		8°	
θ1	6°	8°	10°	
θ2	6°	8°	10°	
θ3	5° 7° 9°			
θ4	5°	7°	9°	



# 5.5 TSSOP14 (Package Outline Dimensions)



Symbol Dimensions In Millimeters						
	MIN	MIN NOM I				
Α		_	1.20			
A1	0.05	1 <del></del> 1	0.15			
A2	0.90	1.00	1.05			
A3	0.34	0.44	0.54			
b	0.20	_	0.28			
b1	0.20	0.22	0.24			
С	0.10 — 0.19					
c1	0.10	0.10 0.13 0				
D	4.86	4.96	5.06			
E	6.20	6.40	6.60			
E1	4.30	4.40	4.50			
е		0.65 BSC				
L	0.45	0.60	0.75			
L1		1.00 REF				
L2		0.25 BSC				
R	0.09	_	_			
R1	0.09	-				
S	0.20	<u> </u>				
01	0°		8°			
θ2	10°	12°	14°			
θ3	10° 12° 14°					

## 6. Related Parts

Part Number	Description
COS6042	24kHz, 0.5μA, Nano-Power Op Amps, 1.4V to 5.5V Supply
COS8042	160MHz, 5.5mA, High Speed Op Amps, 3V to 12V Supply
COS2172	10MHz, 1.2mA, RRIO Op Amps, 4.5 to 40V Supply
COS2333	350kHz, 18μA, Precision Op Amps, 1.8 to 5.5V Supply, Zero Drift, Vos<10μV
COS8552	1.5MHz, 55μA, Precision Op Amps, 1.8 to 5.5V Supply, Zero Drift, Vos<10μV
COS2388	9MHz, 570μA, Precision Op Amps, 1.8 to 5.5V Supply, Zero Drift, Vos<10μV
COS2227	10MHz, 1.3mA, Precision Op Amps, 4.5 to 36V Supply, Vos<50μV
COS2182	5MHz, 580μA, RRIO Precision Op Amps, 4.5 to 40V Supply, Vos<50μV
COS620	1.5MHz, 1.3mA, Instrumentation Amps, 4.5 to 36V Supply, Vos<50µV
COSINA333	150kHz, 65μA, Instrumentation Amps, 1.8 to 5.5V Supply, Vos<25μV